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### LOW RIPPLE VOLTAGE REGULATOR WITH EXTERNAL TRANSISTOR

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NO. EA-043-111116

## OUTLINE

The RN5RF Series are CMOS-based voltage regulator ICs which control external driver transistors with high ripple rejection, high accuracy output voltage, low supply current. Each of these voltage regulator ICs consists of a voltage reference unit, an error amplifier, output voltage setting resistor, short circuit current limiting circuit and chip enable circuit. These ICs are suitable for constructing regulators with ultra low dropout voltage and an output current in the range of several tens of mA and several hundreds mA. In addition to low supply current by CMOS process, chip enable function can be used to conserve battery life during standby.

Furthermore, a supreme ripple rejection and a transient response are suitable for portable communicator such as cell phones, PDAs, walky talkies. SOT23-5 (Mini Mold) package is available.

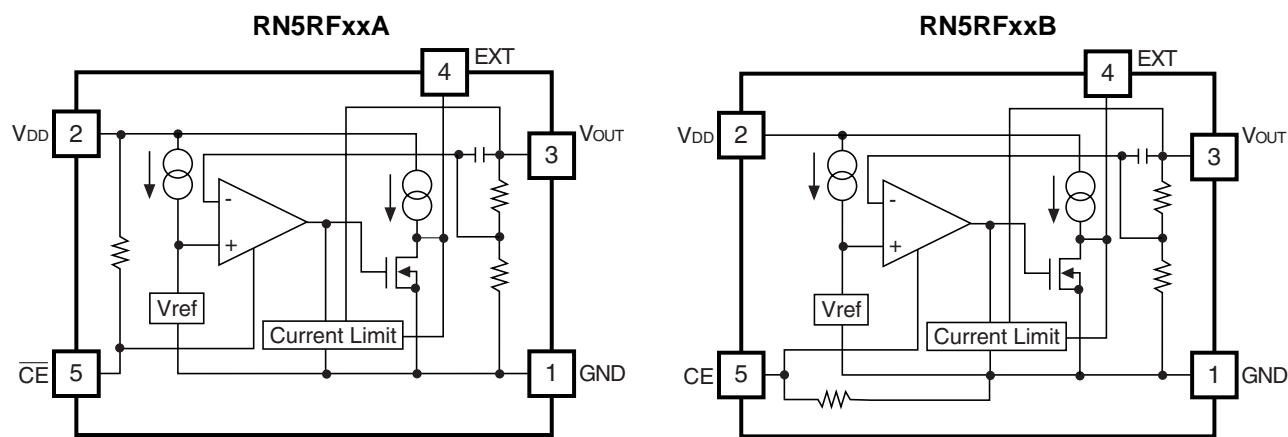
## FEATURES

- Supply Current ..... Typ. 30 $\mu$ A
- Supply Current (Standby) ..... Typ. 0.1 $\mu$ A
- Output Voltage Accuracy .....  $\pm 2\%$
- Ripple Rejection ..... Typ. 60dB (f=1kHz)
- Dropout Voltage ..... Typ. 0.1V ( $I_{OUT}=100\text{mA}$ , dependent on External Tr.)
- Temperature-Drift Coefficient of Output Voltage ..... Typ.  $\pm 100\text{ppm}/^{\circ}\text{C}$
- Line Regulation ..... Typ. 0.05%/V
- Output Voltage Range ..... 1.2V to 6.0V (0.1V steps)  
(For other voltages, please refer to MARK INFORMATION.)
- Package ..... SOT-23-5
- Current Limit for external Tr. .... Current limit Typ. 8mA

## APPLICATIONS

- Power source for battery-powered equipment
- Power source for hand-held communication equipment, cameras, and VCRs
- Power source for home appliances

BLOCK DIAGRAMS

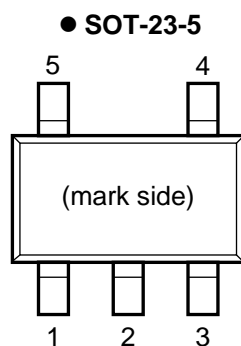


SELECTION GUIDE

The output voltage and CE pin polarity for the ICs can be selected at the user’s request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
RN5RFxx*A-TR-FE	SOT-23-5	3,000 pcs	Yes	Yes
xx: The output voltage can be designated in the range from 1.2V (12) to 6.0V (60) in 0.1V steps. (For other voltages, please refer to MARK INFORMATION.)				
* : CE pin polarity are options as follows (A) "L" active (B) "H" active				

## PIN CONFIGURATION



## PIN DESCRIPTION

● SOT-23-5

Pin No	Symbol	Pin Description
1	GND	Ground Pin
2	V <sub>DD</sub>	Input Pin
3	V <sub>OUT</sub>	Output Pin
4	EXT	External Transistor Drive Pin (CMOS Output)
5	$\overline{\text{CE}}$ or CE	Chip Enable Pin

## ABSOLUTE MAXIMUM RATINGS

Symbol	Item	Rating	Unit
$V_{IN}$	Input Voltage	12.0	V
$V_{CE}$	Input Voltage ( $\overline{CE}$ or CE)	-0.3 to $V_{IN}+0.3$	V
$V_{EXT}$	EXT Output Voltage	-0.3 to $V_{IN}+0.3$	V
$I_{EXT}$	EXT Output Current	50	mA
$P_D$	Power Dissipation* (SOT-23-5)	420	mW
$T_{opt}$	Operating Temperature Range	-40 to 85	°C
$T_{stg}$	Storage Temperature Range	-55 to 125	°C

\*) For Power Dissipation, please refer to PACKAGE INFORMATION.

### ABSOLUTE MAXIMUM RATINGS

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field.

The functional operation at or over these absolute maximum ratings is not assured.

### RECOMMENDED OPERATING CONDITIONS (ELECTRICAL CHARACTERISTICS)

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such conditions by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

## ELECTRICAL CHARACTERISTICS

## • RN5RFxxA

T<sub>opt</sub>=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V <sub>OUT</sub>	Output Voltage	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V I <sub>OUT</sub> =50mA	V <sub>OUT</sub> ×0.98		V <sub>OUT</sub> ×1.02	V
I <sub>OUT</sub>	Output Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V		1.0 <sup>*1</sup>		A
I <sub>EXT</sub>	EXT Current	V <sub>IN</sub> =4.0V, V <sub>EXT</sub> =2.0V	5	8	15	mA
ΔV <sub>OUT</sub> /ΔI <sub>OUT</sub>	Load Regulation	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V 1mA≤I <sub>OUT</sub> ≤100mA	-60		60	mV
V <sub>DIF</sub>	Dropout Voltage	I <sub>OUT</sub> =100mA, I <sub>OUT</sub> =0mA		0.1	0.2	V
I <sub>SS</sub>	Supply Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V		30	50	μA
I <sub>standby</sub>	Standby Current	V <sub>IN</sub> =10.0V	0.01	0.10	1.00	μA
I <sub>EXTleak</sub>	EXT Leakage Current				0.5	μA
ΔV <sub>OUT</sub> /ΔV <sub>IN</sub>	Line Regulation	I <sub>OUT</sub> =50mA V <sub>OUT</sub> +0.5V≤V <sub>IN</sub> ≤10V	0.00	0.05	0.30	%/V
R <sub>R</sub>	Ripple Rejection	f=1kHz, sinusoidal 0.5Vp-p V <sub>IN</sub> -V <sub>OUT</sub> =1.0V		60		dB
V <sub>IN</sub>	Input Voltage				10	V
V <sub>EXT</sub>	EXT Output Voltage				10	V
ΔV <sub>OUT</sub> /ΔT <sub>opt</sub>	Output Voltage Temperature Coefficient	I <sub>OUT</sub> =10mA -40°C≤T <sub>opt</sub> ≤85°C		±100		ppm/°C
R <sub>PU</sub>	Pull up resistance for CE pin			4		MΩ
V <sub>CEH</sub>	$\overline{\text{CE}}$ Input Voltage “H”		1.5		V <sub>IN</sub>	V
V <sub>CEL</sub>	$\overline{\text{CE}}$ Input Voltage “L”		0.00		0.25	V

\*1) The output current depends on the performance of external PNP transistor. Use External PNP transistor of a low saturation type, with an h<sub>FE</sub> between 100 and 300.

\*) With respect to Test Circuit, refer to Typical Application.

## • RN5RFxxB

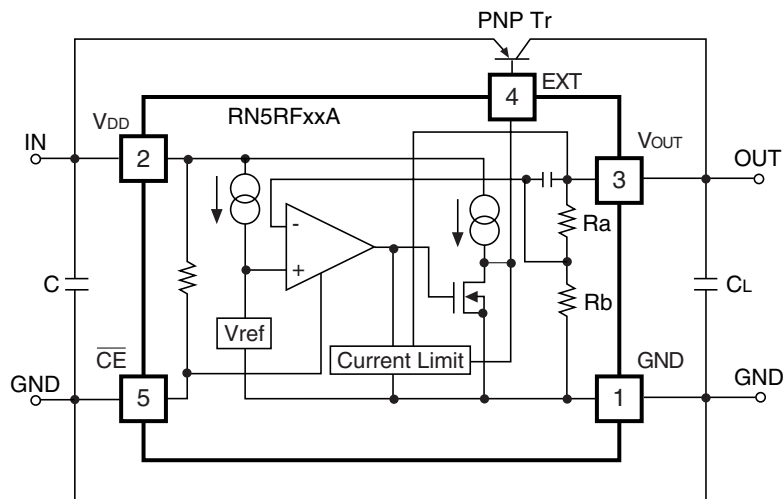
T<sub>opt</sub>=25°C

Symbol	Item	Conditions	Min.	Typ.	Max.	Unit
V <sub>OUT</sub>	Output Voltage	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V I <sub>OUT</sub> =50mA	V <sub>OUT</sub> ×0.98		V <sub>OUT</sub> ×1.02	V
I <sub>OUT</sub>	Output Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V		1.0 <sup>*1</sup>		A
I <sub>EXT</sub>	EXT Current	V <sub>IN</sub> =4.0V, V <sub>EXT</sub> =2.0V	5	8	15	mA
ΔV <sub>OUT</sub> /ΔI <sub>OUT</sub>	Load Regulation	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V 1mA≤I <sub>OUT</sub> ≤100mA	-60		60	mV
V <sub>DIF</sub>	Dropout Voltage	I <sub>OUT</sub> =100mA		0.1	0.2	V
I <sub>SS</sub>	Supply Current	V <sub>IN</sub> -V <sub>OUT</sub> =1.0V I <sub>OUT</sub> =0mA		30	50	μA
I <sub>standby</sub>	Standby Current	V <sub>IN</sub> =10.0V	0.01	0.10	1.00	μA
I <sub>EXTleak</sub>	EXT Leakage Current				0.5	μA
ΔV <sub>OUT</sub> /ΔV <sub>IN</sub>	Line Regulation	I <sub>OUT</sub> =50mA V <sub>OUT</sub> +0.5V≤V <sub>IN</sub> ≤10V	0.00	0.05	0.30	%/V
R <sub>R</sub>	Ripple Rejection	f=1kHz, sinusoidal 0.5Vp-p V <sub>IN</sub> -V <sub>OUT</sub> =1.0V		60		dB
V <sub>IN</sub>	Input Voltage				10	V
V <sub>EXT</sub>	EXT Output Voltage				10	V
ΔV <sub>OUT</sub> /ΔT <sub>opt</sub>	Output Voltage Temperature Coefficient	I <sub>OUT</sub> =10mA -40°C≤T <sub>opt</sub> ≤85°C		±100		ppm/°C
R <sub>PD</sub>	Pull down resistance for CE pin			4		MΩ
V <sub>CEH</sub>	CE Input Voltage “H”		1.5		V <sub>IN</sub>	V
V <sub>CEL</sub>	CE Input Voltage “L”		0.00		0.25	V

\*1) The output current depends on the performance of external PNP transistor. Use External PNP transistor of a low saturation type, with an h<sub>FE</sub> between 100 and 300.

\*) With respect to Test Circuit, refer to Typical Application.

## OPERATION



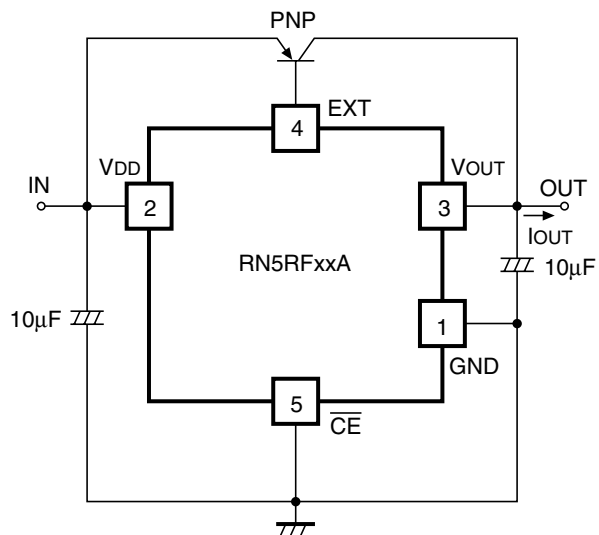
In these ICs, Output Voltage  $V_{OUT}$  is detected by feed-back resistors,  $R_A$  and  $R_B$  and the detected output voltage is compared with a reference voltage by the error amplifier so that the base current of an external PNP Transistor can be adjusted and the output voltage  $V_{OUT}$  is able to be regulated.

The base current of an external  $Tr$  is monitored and controlled by an internal base current limit circuit to keep current within a proper range. Furthermore, the other current limit circuit prevents a problem which is that a base current increases sharply when an input voltage,  $V_{IN}$  becomes lower than set output voltage.

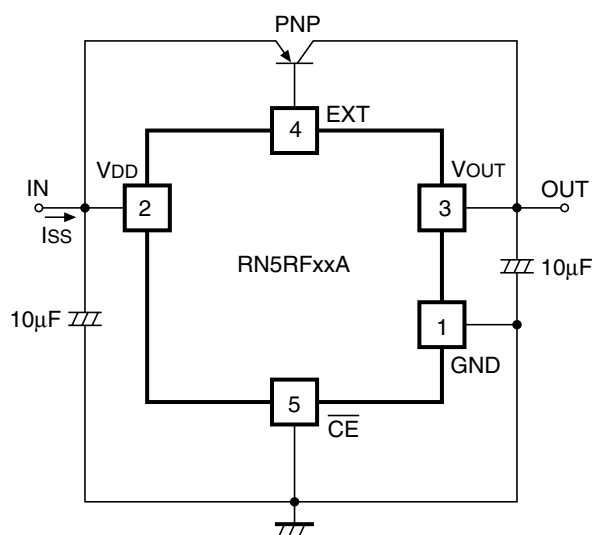
### Notes on selecting external components

- (1) On external PNP transistor  
Be careful of output current, input voltage and power dissipation of an external PNP Transistor. External PNP Transistor with a low  $V_{CE}(\text{sat})$  and an  $h_{FE}$  between 100 and 300 is suitable.
- (2) On phase compensation in these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, be sure to use a capacitor  $C_L$  (tantalum type) with a capacitance of  $10\mu\text{F}$  or more. There may be the case the loop oscillation takes place when a tantalum capacitor  $C_L$  with a large ESR is used, so select the  $C_L$  carefully with considering the frequency characteristics also.

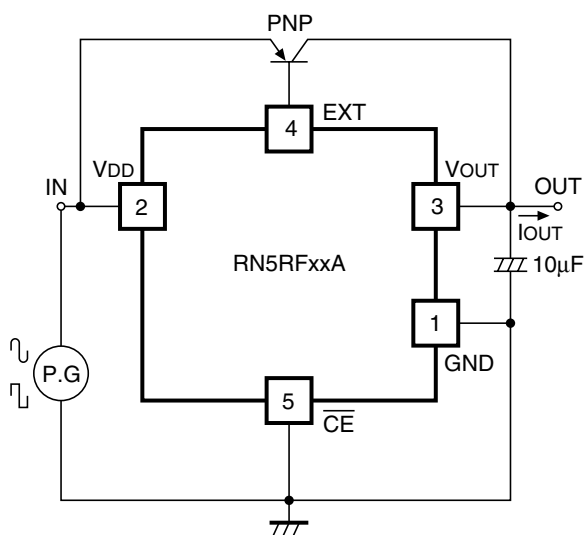
## TEST CIRCUITS



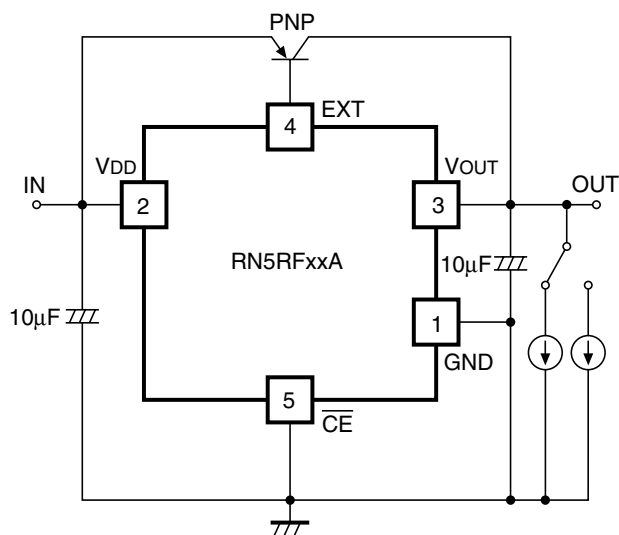
**Basic Test Circuit**



**Test Circuit for Supply Current**



**Test Circuit for Ripple Rejection and Line Transient Response**

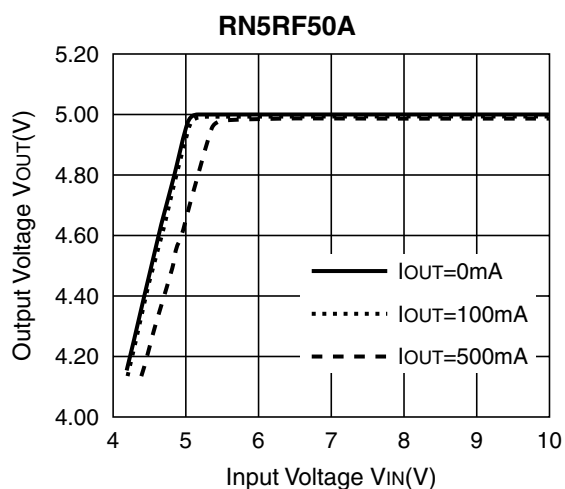
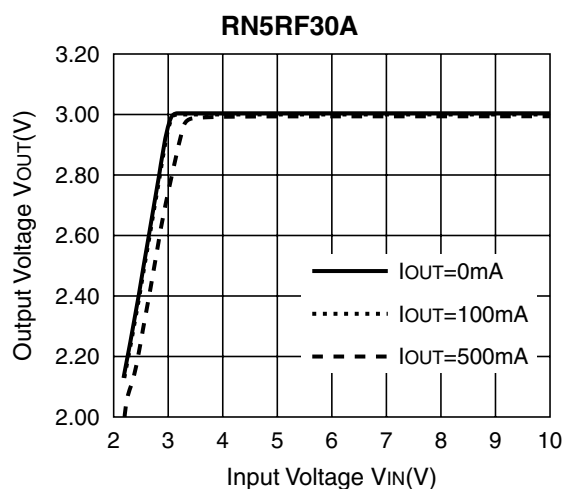


**Test Circuit for Load Transient Response**

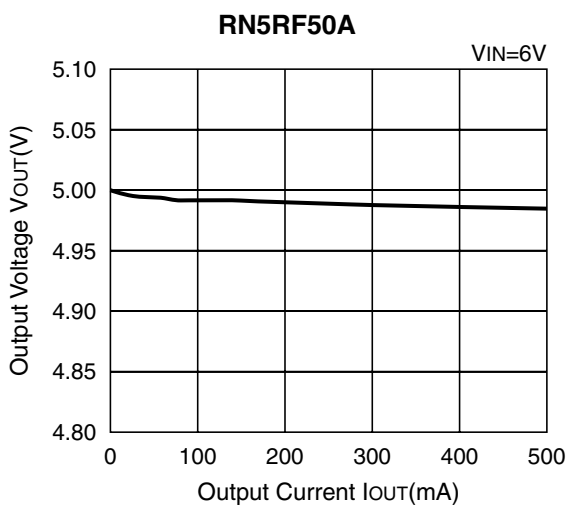
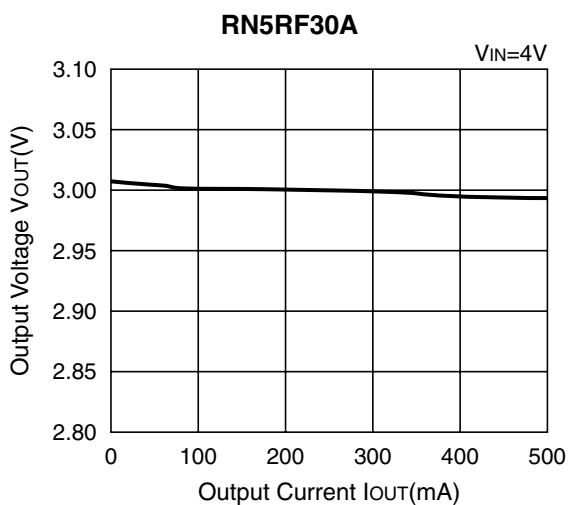


## TYPICAL CHARACTERISTICS

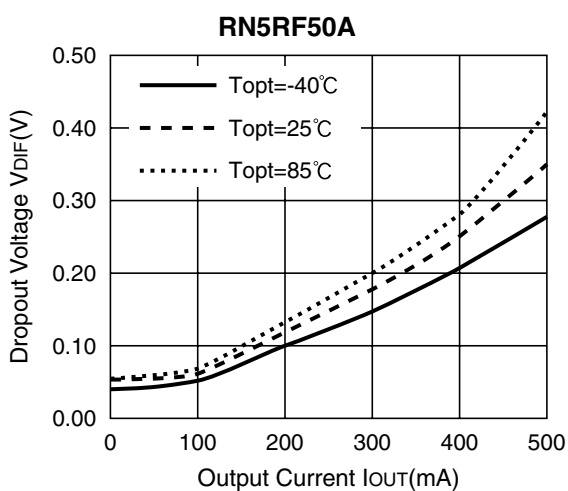
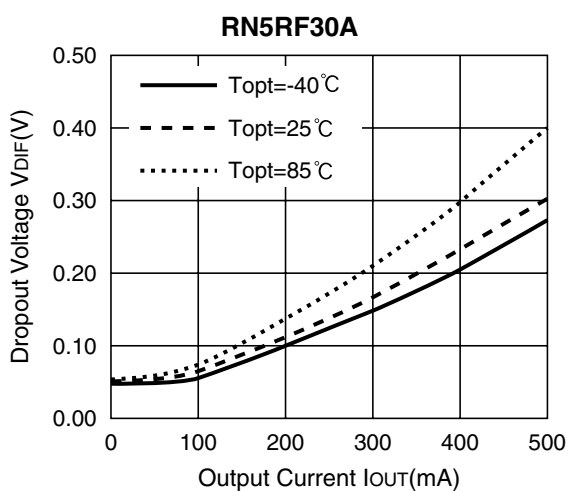
### 1) Output Voltage vs. Input Voltage ( $T_{opt}=25^{\circ}\text{C}$ )



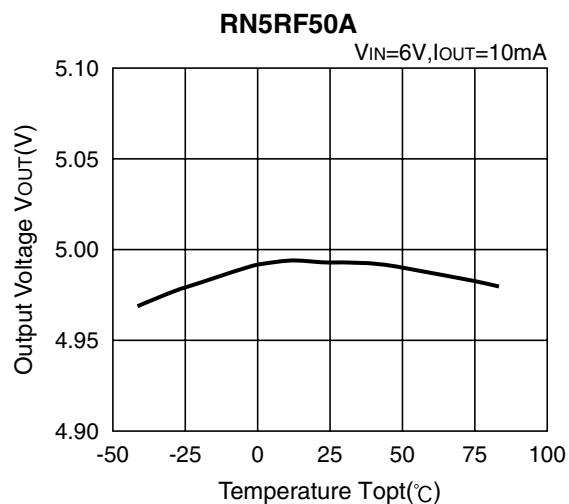
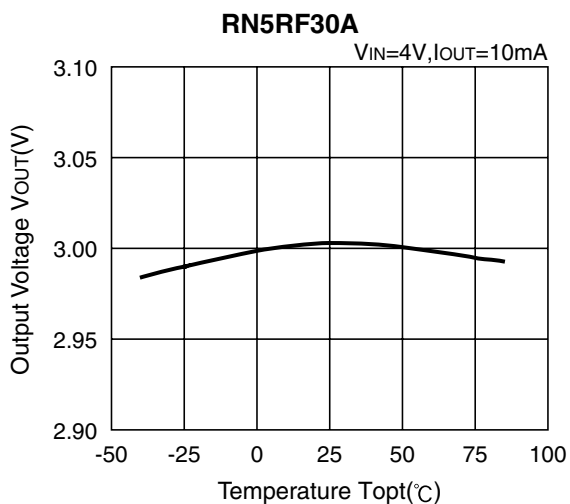
### 2) Output Voltage vs. Output Current ( $T_{opt}=25^{\circ}\text{C}$ )



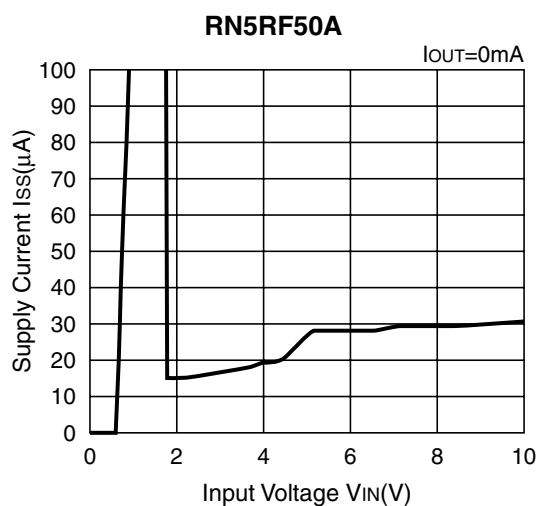
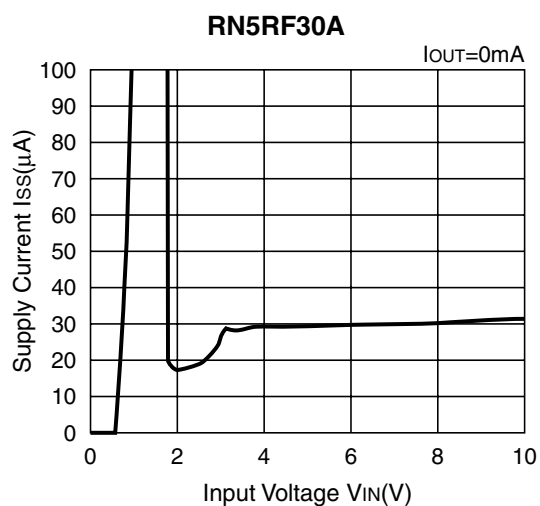
### 3) Dropout Voltage vs. Output Current



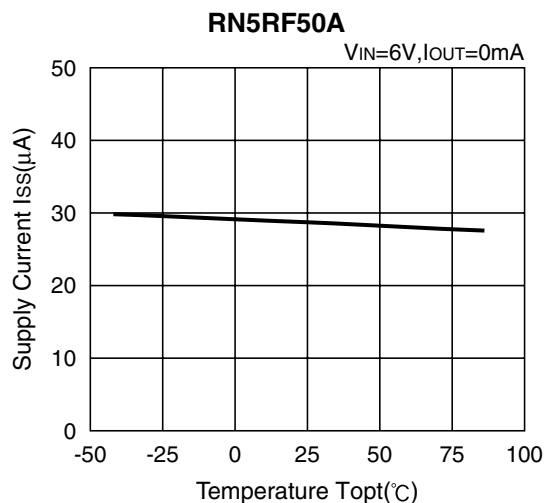
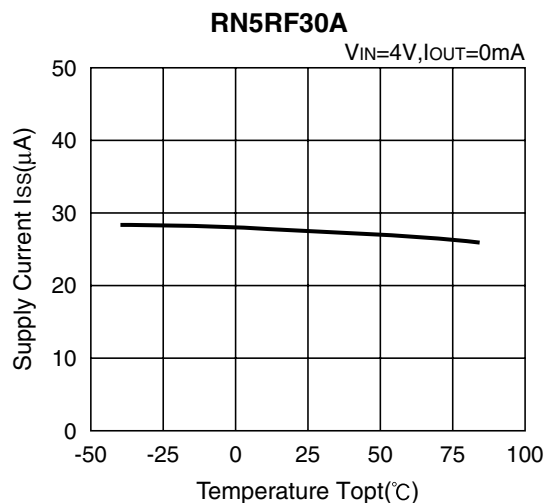
4) Output Voltage vs. Temperature



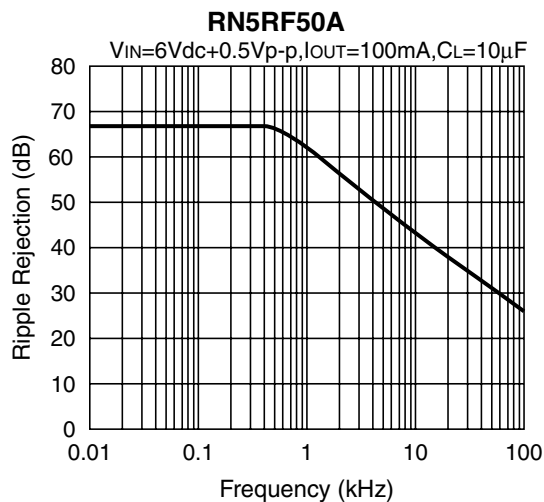
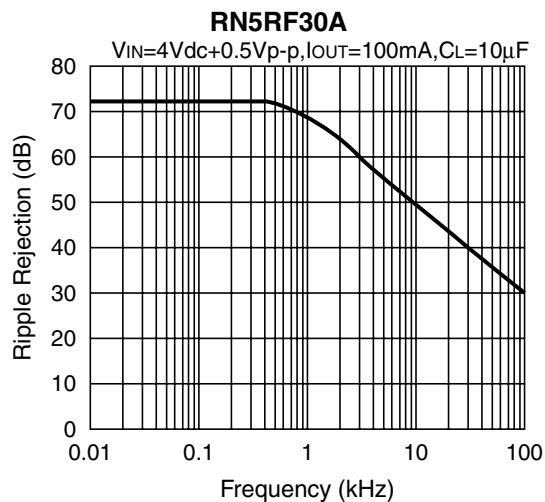
5) Supply Current vs. Input Voltage (Topt=25°C)



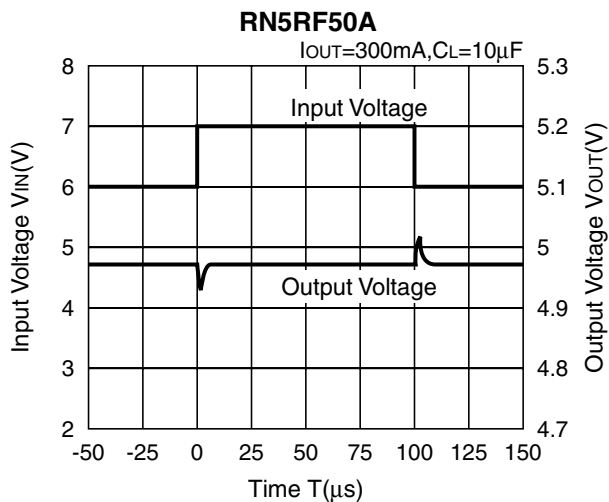
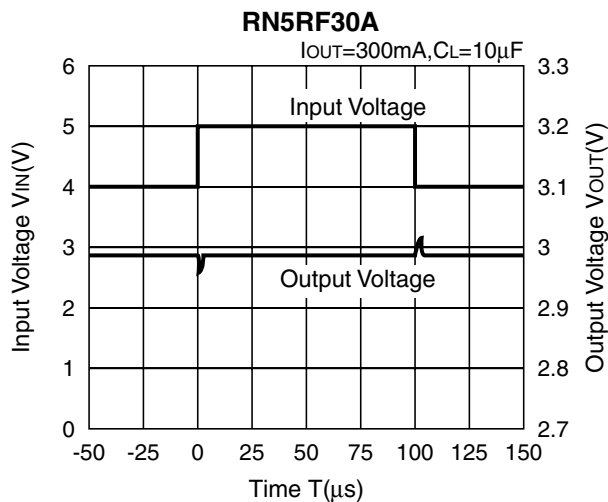
6) Supply Current vs. Temperature



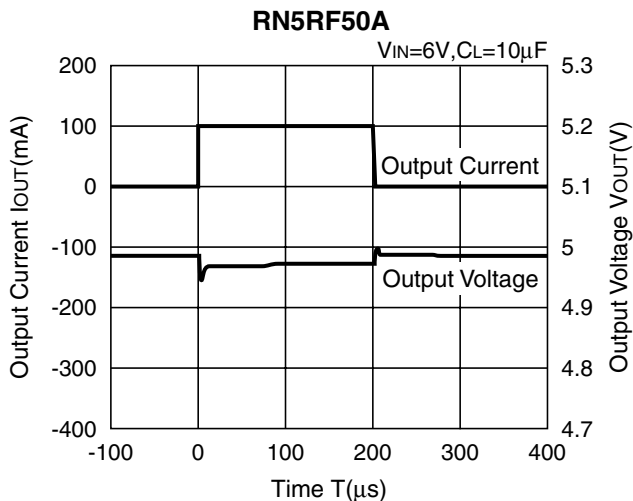
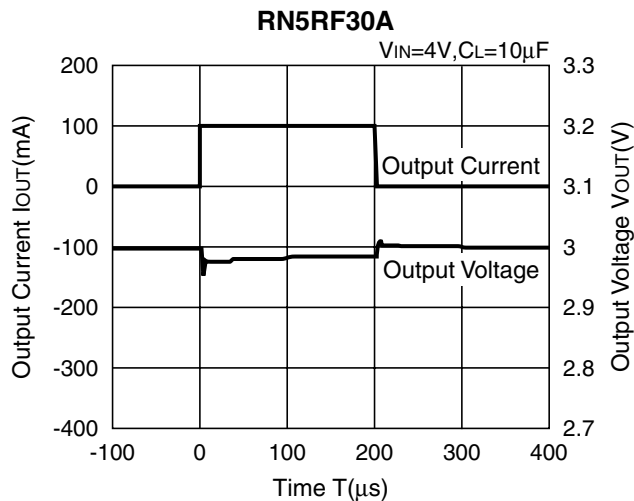
7) Ripple Rejection vs. Frequency (T<sub>opt</sub>=25°C)



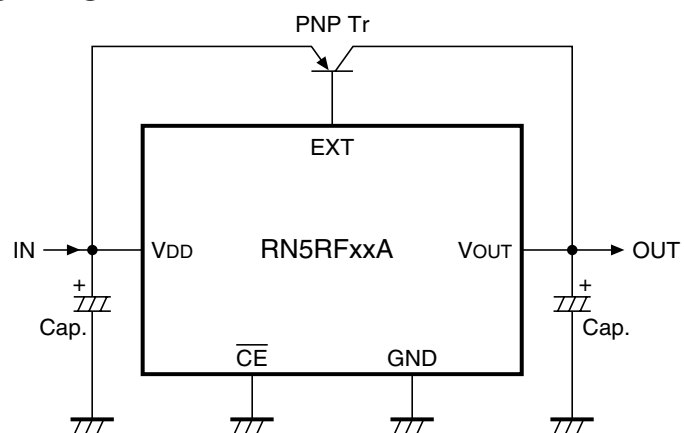
8) Line Transient Response (T<sub>opt</sub>=25°C)



9) Load Transient Response (T<sub>opt</sub>=25°C)



## TYPICAL APPLICATION



Components

Transistor: 2SB766A

Capacitor: 10µF (Tantalum type)



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Ricoh continually strives to promote customer satisfaction, and shares the achievements of its management quality improvement program with people and society.



■ Ricoh awarded ISO 14001 certification.

The Ricoh Group was awarded ISO 14001 certification, which is an international standard for environmental management systems, at both its domestic and overseas production facilities. Our current aim is to obtain ISO 14001 certification for all of our business offices.

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Ricoh completed the organization of the Lead-free production for all of our products. After Apr. 1, 2006, we will ship out the lead free products only. Thus, all products that will be shipped from now on comply with RoHS Directive.